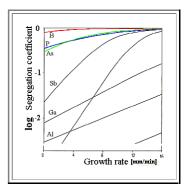
Exercise 4.4-1

All Quick Questions to

4. Getting Started

Subchapter 4.1: Input to Si Processing in an Industrial Environment

- List (and discuss briefly) some essential inputs to a chip factory.
- What is the essential process for producing raw (= metallurgical) Si and what is the major use for this Si?
- Go through the essential of Si single crystal growth by the CZ technique. Give numbers and discuss in-situ doping, keeping the crystal dislocations-free, and any remaining problems.
- Describe shortly the essentials of how to obtain clean, doped poly-Si as needed for single crystal growth
- Where and why is a CVD process involved in making electronic grade Si?
- Describe the phenomenon of segregation. How does it impact Si crystal growth?
- Given the diagram on the right, discuss:
 - What a segregation coefficient of , e.g., 10^{-2} means in terms of the concentration in the crystal in the beginning and the end of the crystal growth process if the initial concentration in the melt is 10^{-6}
 - Why you prefer As to Sb as a dopant during crystal growth.



- Why is extreme flatness an essential condition for standard Si wafers?
- Why is it possible to keep wafers completely free of dislocations, but not of "microdefects" = agglomerates of point defects?

Subchapter 4.2: Other Semiconductor Growth Technologies

- Describe some problems encountered (and the solutions) when growing III-V single crystals.
- What are the incentives for trying to get SiC "to work"? Describe the specific problems encountered when growing SiC single crystals.
- Provide and describe major products not based on single crystal semiconductors.
- Explain the follwong abbreviations and give possible uses: a-Si:H, µc-Si:H, CIGS.

Subchapter 4.3: Infrastructure

- "Cleanroom class 100" means roughly....?
- Describe the effects of particles on, and contamination in the chip.
- The electrically crucial area of an integrated transisitor is (50 × 300 × 300) nm³. The lattice constant of Si is roughly 0.5 nm; there are atoms per elementry cell. An Au concetration of 1 ppb "kills" the transistor. How many Au atoms can you tolerate in your transistor? If you touch a gold ring and 1 out of 1 billion surface atoms gets stuck on your finger how many roughly are now on your skin?